



FutureChips

Postdoc Programme

Dr. Pauli Kuosmanen
Director
Research and Innovation Services



Co-funded by
the European Union

Programme 10:30-11:30 EEST

- Welcome and introduction to Tampere University **Pauli Kuosmanen**
- FiCCC + Chips from Tampere **Petri Räsänen, Pasi Pylväs**
- FutureChips - the open call **Jörg Langwaldt**
- Research theme 1: Advanced compound materials and heterostructures
 - **Mircea Guina** [Optoelectronics Research Centre](#)
 - **Goëry Genty** [Ultrafast Photonics](#)
- Research theme 2: Novel Architectures
 - **Sayani Majumdar** [CMOS and Beyond](#)
- Research theme 4: Advanced packaging
 - **Matti Mäntysalo** [Electronics research centre](#)
 - **Juha Toivonen** [Applied Optics](#)
- 11:25-11:30 QA and Closure



Introduction to Tampere University



Tampere, Finland

- Tampere is a vibrant, clean and safe city. It consistently tops surveys as the most desirable city to live, study and do business in Finland.
- With a population of 260,000, Tampere is Finland's third-largest city. One in every five residents is a student in secondary or higher education.
- Tampere is internationally recognised as one of the world's top five semiconductor hubs and a major European chip design and photonics cluster.



Tampere University in brief

**Multidisciplinary,
the 2nd largest
university in Finland**



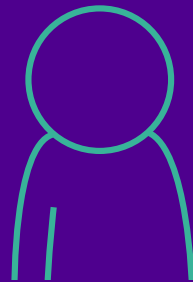
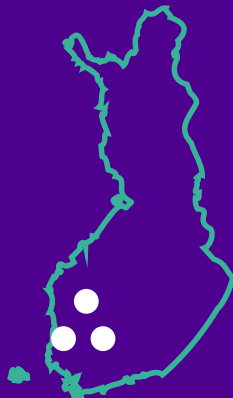
7 faculties



10 fields of education

Our locations:

Tampere
Seinäjoki
Pori



23,200 students
105 nationalities
9% internationals

4,400 employees
83 nationalities
21% internationals

Our focus areas:

Technology
Health
Society



Operating
revenue

390 M€

Research and
development
funding

119 M€

We work together to
build a sustainable
world.

We aim for
carbon neutrality
and promote
nature positivity



Our international strategy 2030



A thriving university community

1. We are a diverse and inclusive community that promotes participation and provides equal opportunities for everyone to succeed
2. Everyone has the opportunity to internationalise
3. We follow open recruitment practices to attract the most qualified candidates
4. Our international staff and students commit to and engage with the University and Finnish society

An internationally esteemed research university

1. We lead international research
2. We are a European university
3. We promote the global utilisation of research-based knowledge

An educator of world-changing experts

1. Internationality is integrated into all our degree programmes
2. Our degree programmes are of high quality and are delivered responsibly

A strong partner and active societal influencer

1. We have a strategic approach to internationalisation
2. We make an international impact together with our stakeholders
3. Our international cooperation is responsible

Wide-ranging research across disciplinary boundaries

- Our key strength is research in the fields of **technology**, **health** and **society**.
- We conduct research responsibly and actively promote open science.
- State-of-the-art research infrastructures are an integral part of our research environment.



Collaborative R&I: TAU is #14 in Pillar 2 RIA/IA

Horizon Europe collaborative research and innovation actions

14. TAU

Collaborative R&I projects

This is TAU's highest relative ranking among the selected Horizon Europe views.

Interpretation

The collaborative portfolio places TAU in the leading European university peer group.

Benchmark leaders

- | | |
|-----|-----------|
| 1. | KU Leuven |
| 2. | TU Delft |
| 3. | DTU |
| 4. | Aarhus |
| 5. | Gent |
| 14. | TAU |

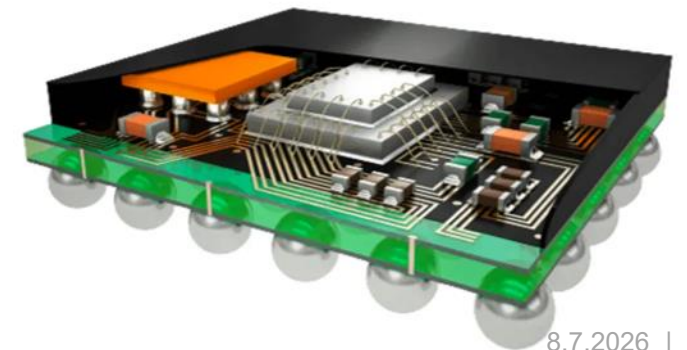
Finnish peers (top): #27 Oulu · #33 Helsinki · #50 Aalto

Full ranking context remains on the detailed comparison slide.

TAU – Chips JU



- Chips Act Large Pilot lines:
 - Advanced Wide Bandgap Semiconductors – System-in-Package Fab
- EU Design Platform (EuroCDP):
 - Develops chip design support for European Industry, especially SME's and startups
 - IMEC; CEA/LETI, Fraunhofer, ...
- Finnish Chip Competence Center:
 - Strengthen the Finnish Chips expertise
 - Tampere, Espoo, Oulu, Joensuu
- Design Enablement Team:
 - Chip Design Team: TAU, CoreHW, VLSI Solution, VTT, Chip Fusion
- EuroCDP FSTP:
 - Support for start-ups and SMEs making use of the Design Platform (220M€ EU + national funding)



Semiconductor research

We coordinate:

- PREIN – Flagship on Photonics Research and Innovation
- Key contact goery.genty@tuni.fi and mircea.guina@tuni.fi and juha.toivonen@tuni.fi

We are partners in:

- **System-on-Chip Hub research centre**
- Key contact timo.hamalainen@tuni.fi
- **System-in-Package Fabrication (SiPFAB) EU-pilot line for wide bandgap (WBG) chip packaging**
- Key contact jukka.viheriala@tuni.fi and sayani.majumdar@tuni.fi





**Human
Potential
Unlimited.**

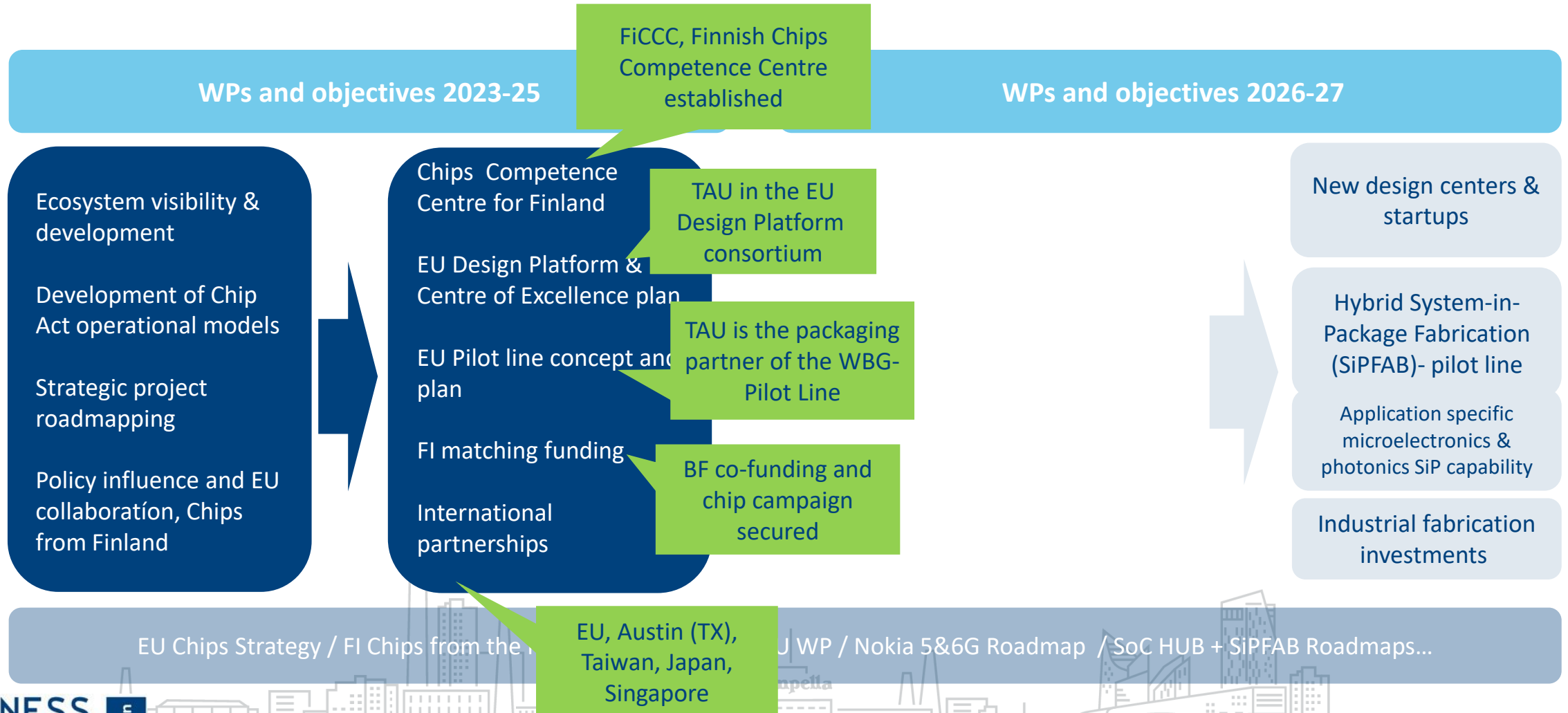
Chips from Tampere 1-2

From Pillar 1 in ECA1 to Pillar 2 in ECA2

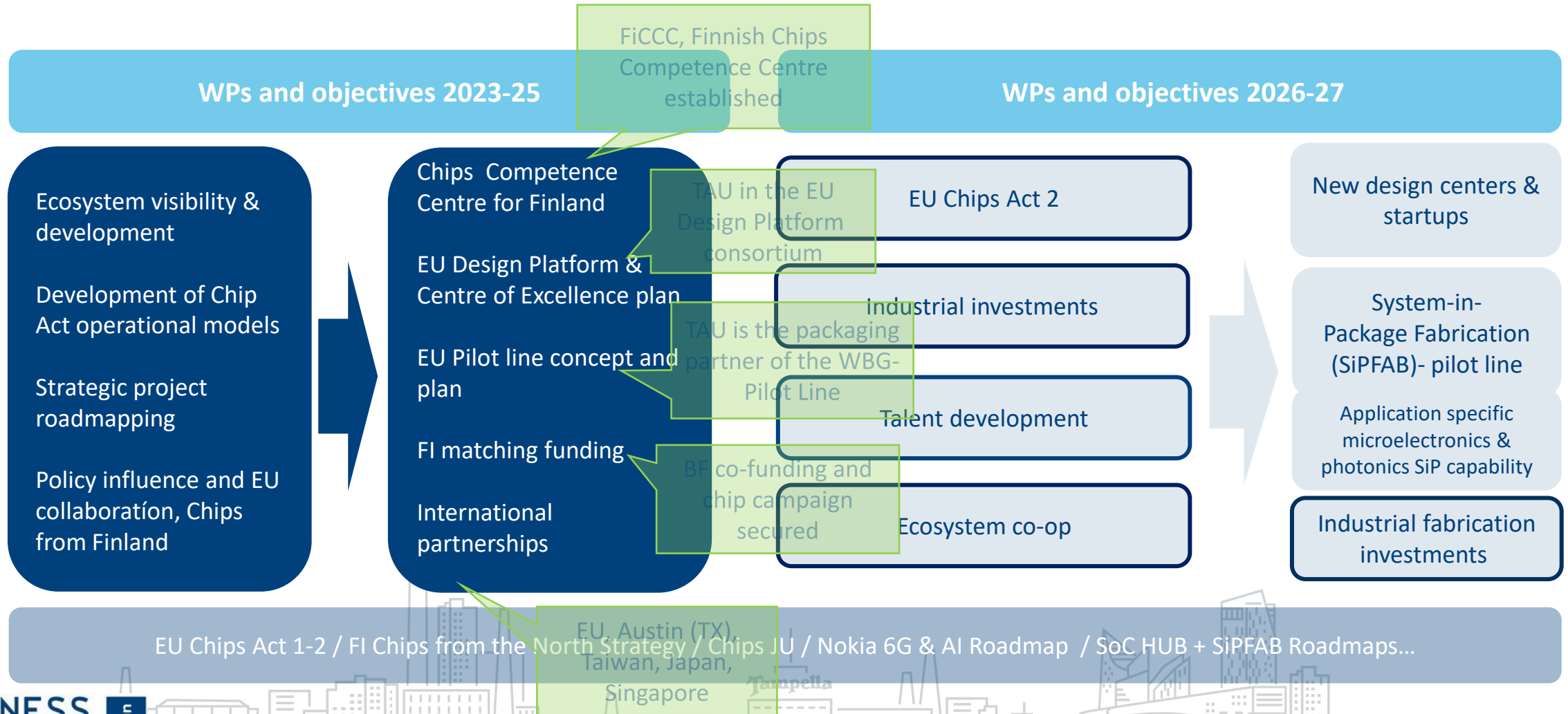
Petri Räsänen
Senior Director
Business Tampere Ltd.

petri.rasanen@business tampere.com

Chips from Tampere - phase 1



Chips from Tampere – phase 2





Tampere Chip ecosystem

- The Finnish Chips Competence Centre FiCCC brings together top experts in the field and accelerates digitalization across industries. FiCCC supports the development of competitive chips and operates from Tampere University.
- The Tampere region is among the world's top 5 semiconductor hubs and a major European chip design and photonics cluster.
- Tampere has developed a strong cluster of companies focused on photonic systems, semiconductors, and laser technology, the “Laser Valley.”
- The region hosts 17 semiconductor companies.
- Over 500 professionals in chip design work in Tampere.
- Nokia is one of the largest users of advanced chips in the EU, and a significant portion of its chip development is located in Tampere.
- Europe's leading design service company, Nordic Semiconductors, is in Tampere.

FutureChips

Next-generation semiconductor technologies

Postdoctoral Programme

Horizon Europe - Marie Skłodowska-Curie Action

Contact us: futurechips@tuni.fi

FutureChips webpage <https://projects.tuni.fi/futurechips/>

Call is open until 31 August 2026

- 12 postdoctoral fellowships (36-month) for next-generation semiconductor technologies implemented at:
 - Faculty of Engineering and Natural Sciences
 - Faculty of Information Technology and Communication Sciences.
- 1st **call** for applications (12 fellowships) is open from **July 1 to August 31, 2026**.
- Applicants propose their **preferred specific research project fitting** to one of the four research areas of FutureChips
 - 1. **Advanced compound materials and heterostructures**, 2. **Novel architectures**, 3. **Chip design**, 4. **Advanced packaging**
- Based on the **selected Research area**, the **applicant select the primary academic supervisor** (ie research group leader) listed for the corresponding FutureChips research area.
- Monthly gross salary before taxation €4500 after taxation about €3100.

FutureChips

Next-generation semiconductor technologies

[HOME](#)[ABOUT](#)[RESEARCH AREAS](#)[SUPERVISORS](#)[RESEARCH INFRASTRUCTURE](#)[HOW TO APPLY](#)[SUOMEKSI](#)

FutureChips

FutureChips is a new postdoctoral programme at Tampere University offering 20 excellent researchers a 36-month fellowship in the field of next-generation semiconductor technologies.

The first call for applications (12 fellowships) will be open from July 1 to August 31, 2026. Fellows are expected to relocate to Tampere and to start their fellowship in July 2027.

Four research areas:

- 1. Advanced compound materials and heterostructures**
- 2. Novel architectures**
- 3. Chip design**
- 4. Advanced packaging**

23 Academic Supervisors

- **Theme 1: Advanced compound materials and heterostructures**
 - [Prof Robert Fickler](#)
 - [Prof Goery Genty](#)
 - [Prof Mircea Guina](#)
 - [Prof Regina Gumenyuk](#)
 - [Prof Laetitia Petit](#)
 - [Prof Mika Valden](#)
- **Theme 2: Novel Architectures**
 - [Asst. Prof Mohsin Abbas](#)
 - [Prof Robert Fickler](#)
 - [Adj. Prof Mikko Huttunen](#)
 - [Prof Pekka Jääskeläinen](#)
 - [Asst. Prof Sergey Kruk](#)
 - [Prof Sayani Majumdar](#)
 - [Assoc. Prof. Tapio Niemi](#)
 - [Prof. of Practice Markku-Juhani Saarinen](#)
- **Theme 3: Chip design**
 - [Asst. Prof Mohsin Abbas](#)
 - [Prof Timo D. Hämäläinen](#)
 - [Prof Pekka Jääskeläinen](#)
 - [Asst. Prof Alexandre Mercat](#)
 - [Prof Karri Palovuori](#)
 - [Prof. of Practice Markku-Juhani Saarinen](#)
 - [Asst. Prof Vishnu Unnikrishnan](#)
 - [Prof Mikko Valkama](#)
 - [Prof Jarno Vanne](#)
 - [Asst. Prof Han Zhou](#)
- **Theme 4: Advanced packaging**
 - [Prof Matti Mäntysalo](#)
 - [Prof Juha Toivonen](#)
 - [Assoc. Prof Jukka Viheriälä](#)

<https://projects.tuni.fi/futurechips/>

Mircea Guina

Briefly

Prof. Mircea Guina (Semiconductor Technology): >750 publications, h-index 40, >10 patents, supervised 16 postdocs, >25 PhD candidates. ERC grantee. He has mentored several entrepreneurial teams and he co-founded three deep tech spinoffs related to semiconductor technology: Vexlum, Picophotonics and Reflektron, all located in Tampere. Innovation professor of the year award (2023).

Research outputs and activities of the Supervisor

- [TUNICRIS Research portal](#)
- [Open Researcher and Contributor ID](#)

Research group

[Optoelectronics Research Centre \(ORC\)](#) is the only European group with leading fabrication expertise across all key materials used in optoelectronics, i.e. GaAs, InP, and GaSb material systems. The group has been at the frontier of optoelectronics research in Finland and Europe for more than 30 years, capitalizing on an outstanding range of fabrication processes and characterization expertise.

Research infrastructure

Essential to the success of ORC is the operation of 3 MBE reactors (for synthesis of GaAs-, InP-, and GaSb-based compounds) and complete optoelectronic device processing and characterization lines, including state-of-the-art equipment for coatings, metallization, and lithography, as well as static, spectral, and high-speed modulation characterization. TAU has made significant investment in directly supporting infrastructure related to photonics research and material science in general. The entire infrastructure at TAU related to photonics and advanced clean-room environments (class ISO5 and ISO7) is part of the FinnLight National Infrastructure (<https://finnlight.fi>), which enables access to a comprehensive combination of technologies covering all classes of photonics materials and process lines for device fabrication. It also offers state-of-the-art possibilities for material investigations at nanoscale.

Application - Requirements



- Applicants must:
- **have not** resided or carried out their main activity (e.g. work, studies) in Finland for more than 12 months in the 36 months immediately preceding the application deadline (31 August 2026).
- have a **doctoral degree** in a relevant field (e.g. future electronics, electrical engineering, photonics, micro- and nanotechnology, semiconductor physics, advanced materials, or chip design) by the application deadline of 31 August 2026. Applicants who have successfully defended their doctoral thesis by 31 August 2026, but who have not yet formally been awarded the degree are also eligible to apply. In such cases, the applicant must provide confirmation that the doctoral degree will be awarded at the latest upon starting the employment.
- have the ability to pursue independent scholarly activity.
- have fluent spoken and written English skills.

Application – Submission documents

- **Doctoral degree certificate**
- **Application** using the template and containing:
 - **Research Plan Abstract**
 - **Research Plan** within any of the four research areas of FutureChips
 - **Curriculum Vitae**
 - **List of publications**
 - **Ethics self-assessment**
 - **Motivation letter**

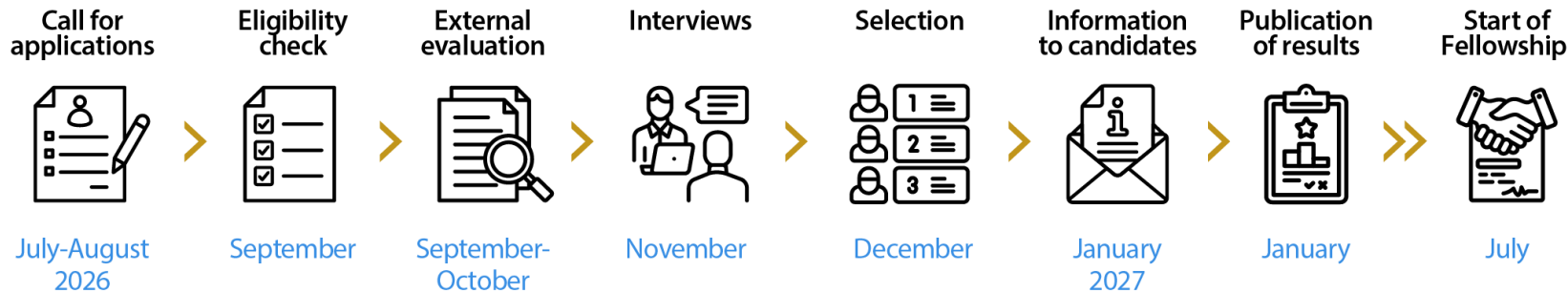
Applications are submitted in the LAURA-system. See the Open Position description, the Guide for Applicants and the Application template.

Evaluation and selection

The applicant will be evaluated based on:

- the applicant's academic merits and demonstrated excellence,
 - the quality and scientific excellence of the research proposal,
 - the feasibility, impact, and implementation of the research proposal,
 - the scientific relevance and significance of the proposed research topic,
 - communication and dissemination skills.
-
- Check: Match of the Research plan with the Research area and academic supervisor, required versus available Research infrastructure

Evaluation and selection



- Each eligible application is evaluated by three independent experts.
- Applications are ranked by scoring.
- The highest ranked will proceed to online interviews.
- Online interviews (25 min) in November, 9.–20.
- Ethics screening.
- Rebuttal opportunities based on procedural errors or factual inaccuracies.
- Recruitment decision at the end of 2026.

WORK IN TAMPERE

QUALITY OF LIFE WORK AND EDUCATION ADVENTURE AND LEASURE

TAMPERE.
FINLAND

- Reciprocal commitment to start the employment by July 2027 is formally agreed upon in a hosting agreement to be signed in early 2027.
- Fellows have to **relocate to Tampere**, Finland.
- Fellowships start at the latest in **July 2027**.

Work in Tampere Finland

Tampere offers a blend of modern urban living and breathtaking natural beauty, world-class innovation and local tradition, work and leisure, warm sunny summer and beautiful snowy winter. It's not just a place to live—it's a place to thrive. Here you will experience the exceptional quality of life that this Finnish gem has to offer for those looking to relocate.

Relocation services

- [Guide for New International Researchers and Their Families](#)
 - Relocation Guides and International Service Points | Formalities | Finnish Culture and Language | Practicalities | Health Care | Finnish Work Culture | Diversity and Inclusion in Academia | Spouses | Families with Children | Cultural Events and Hobbies | Contributor
- [Relocation guide to Tampere](#)
- [International House Tampere](#)
 - International Service Points at city of Tampere host the regional international house
- [Tampere University as an employer](#)
- [Moving to Tampere](#)
- [Working and living in Tampere](#)

More about Finland, Tampere and TAU

- [Visit Finland](#)
- [This is Finland](#)
- [Ministry of Economic Affairs and Employment: Welcome to Finland](#)
- [Visit Tampere](#)
- [Work in Tampere](#)
- [Working at Tampere University](#)
- [Tampere Higher Education Community - our academic playground.](#)
- [FutureChips](#)

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Professor Mircea Guina

Optoelectronics

ORCID 0000-0002-9317-8187

Physics:
Photonics

Professor at the **Faculty of Engineering and Natural Sciences** in the Physics unit, head of ORC research group.

- **Research focus:** Development of optoelectronic devices, III-V semiconductor technology, and photonic integrated systems
- **Expertise in:** molecular beam epitaxy (MBE), semiconductor technology, laser physics, optoelectronic devices and related applications in photonic systems.
- **Collaboration offering:** comprehensive development of novel optoelectronic devices, including advanced semiconductor lasers and detectors for applications in sensing, medicine, communication, and security; MBE fabrication of III-V compounds.

Keywords:

Optoelectronics; Molecular Beam Epitaxy; Photonic Integration; Semiconductor lasers and detectors

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+358 (0)40 849 0004





Future Chips

Topic 1: advance compound materials and heterostructures

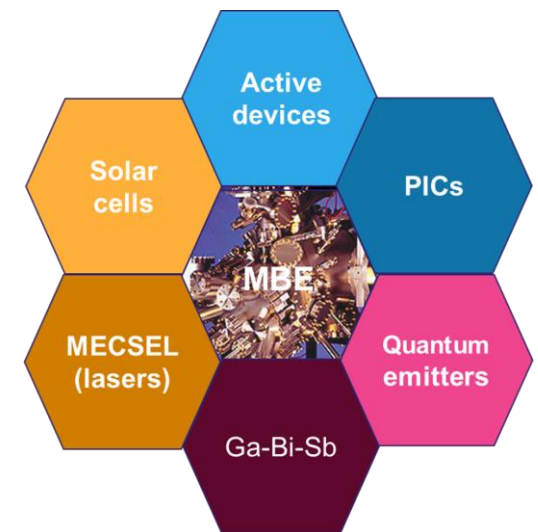
Prof. Mircea GUINA

Faculty of Engineering and Natural Sciences

Tampere University, Finland

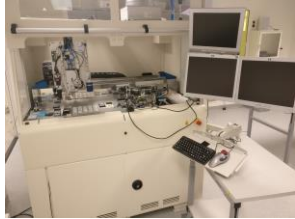
e-mail: mircea.guina@tuni.fi

LinkedIn: [@mircea-guina](#)

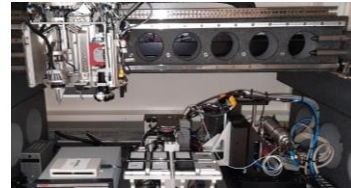


Vertically integrated optoelectronics fabrication

<https://research.tuni.fi/orc/>



- Flip-chip bonding
- Wire bonding
- Bond validation
- Solder deposition



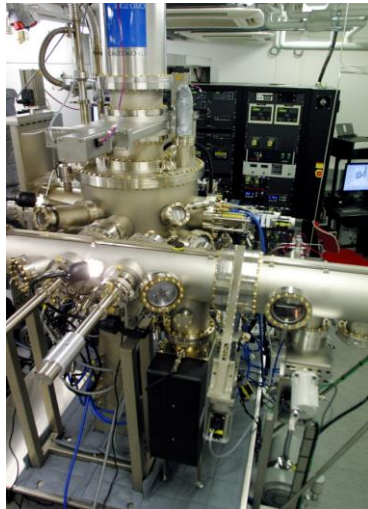
- 3D-micro assembly
- Optical coatings

System level Customer applications

LIDAR	Enviromental sensing
Datacom	Quantum technology
Solar energy	Biomedical technology
Imaging	Process monitoring



- UV Lithography
- NIL
- Etching
- Metal deposit
- Insulators
- Wafer bonding
- Electron beam lithography
- Microscopy / Profilometry



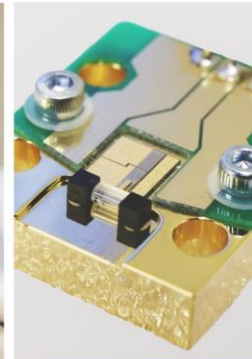
MBE technology
40 years legacy



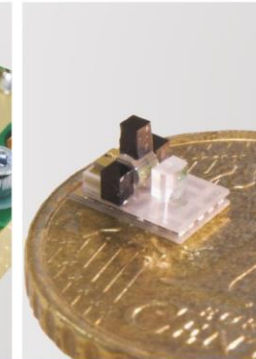
**Wafer
fabrication**



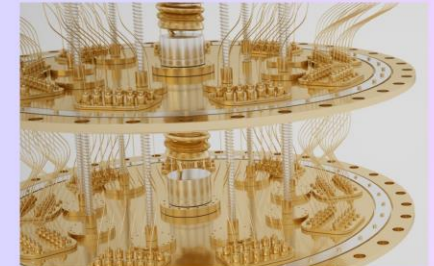
**Wafer level
processing
and
packaging**



**Chip level
packaging**



**Module
sub-assembly**



**External
chip fabs**

Key materials: GaAs, InP, GaSb



Current research topics

(2026)



GROUP

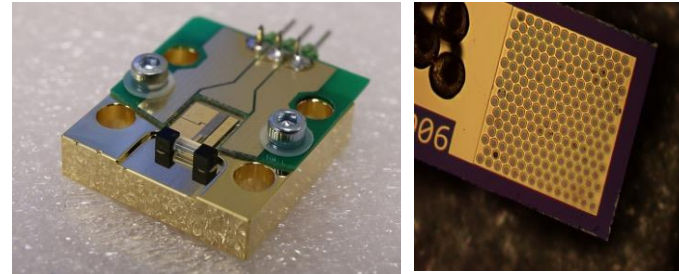
~ 20

Co-Pi Dr. T. Hakkarainen
Co-Pi Prof. J. Viheriälä (ITC)
PostDocs: J. Hilska, H. Tuorila

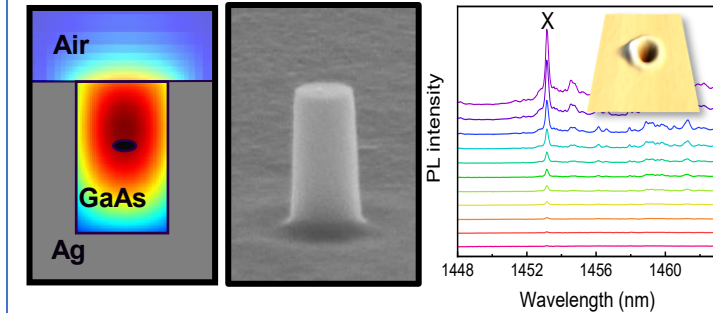
8 PhD students
- 2 finalizing in 2026
6 MSc students
4 BSc students

ENRE support
Senior Scientists:
A. Tukiainen, A. Vlasov

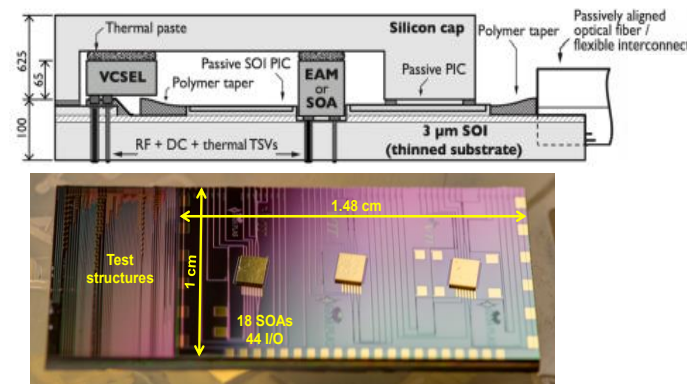
Laser diodes, SLEDs, & VCSEL



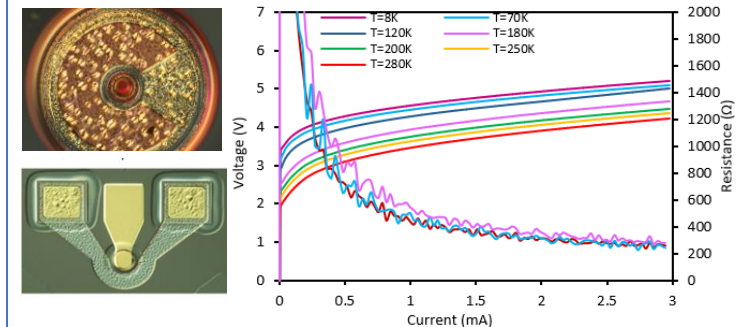
Quantum light sources



Photonic integrated circuits (PICs)



Cryogenic optoelectronics

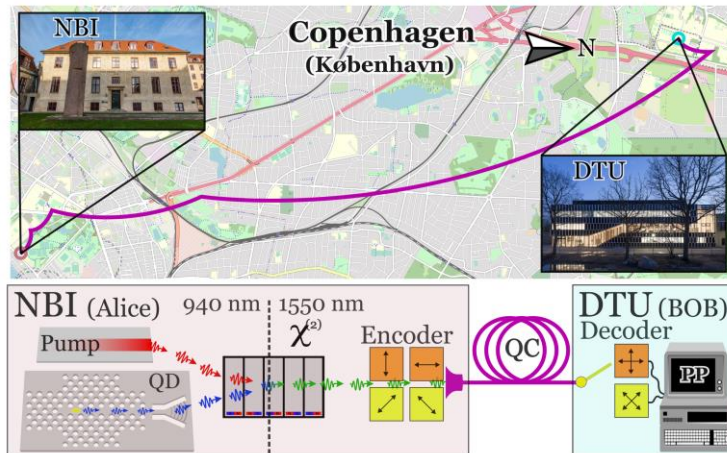


Quantum sources based on GaSb QDs:

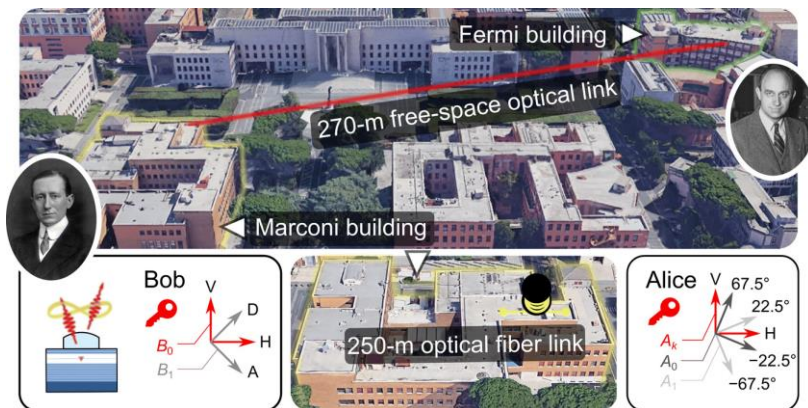
Fiber-compatible on-demand quantum light sources

Best QDs: 900nm InGaAs and 780nm GaAs

– high transmission losses in fibers and air



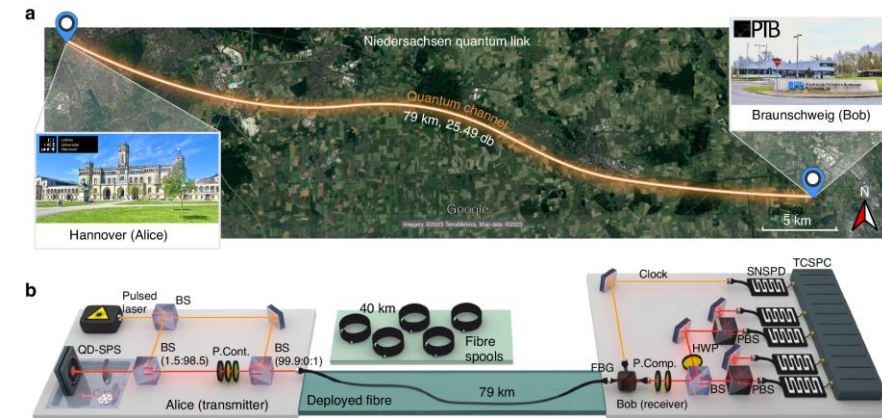
M. Zahidy et al. npj Quantum Information 10, 2 (2024).



F. B. Basset et al. Sci. Adv. 7, 6379 (2021)

Fiber-compatible: 1550 nm InGaAs QDs

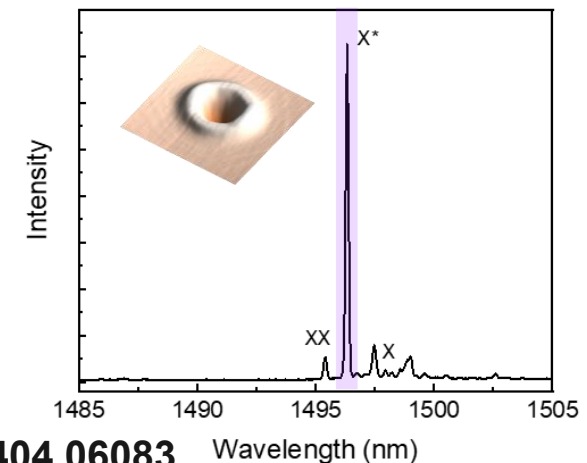
– current QKD SoA with 4.8×10^{-5} key bits/pulse



J. Yang et al. Light: Sci. & Appl. 13, 150 (2024)

Our Telecom GaSb QDs

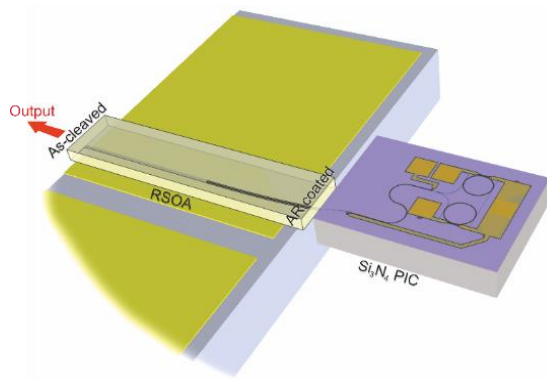
- Properties matching the best short wavelength QD materials
- But at fiber-compatible wavelength



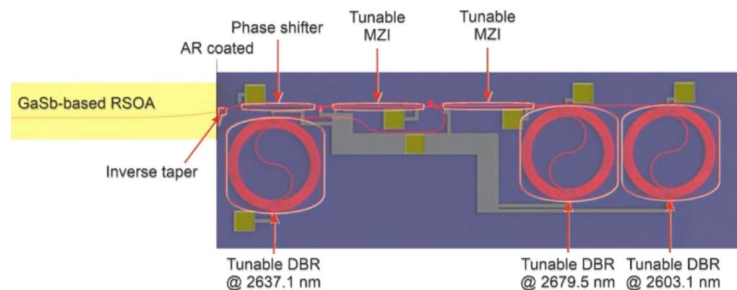
Teemu Hakkarainen: <https://arxiv.org/abs/2404.06083>

GaSb/PIC Hybrid Laser

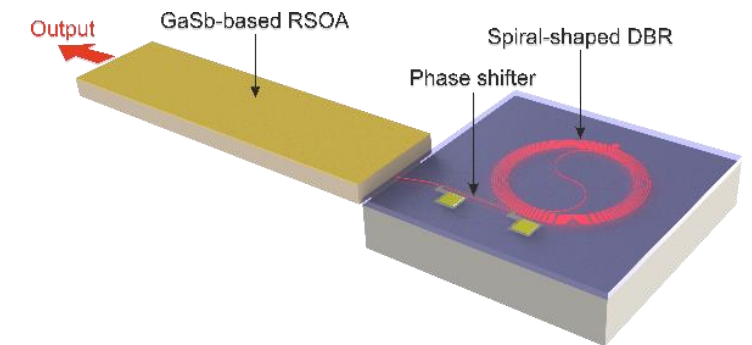
Widely tunable laser



Discretely tunable laser

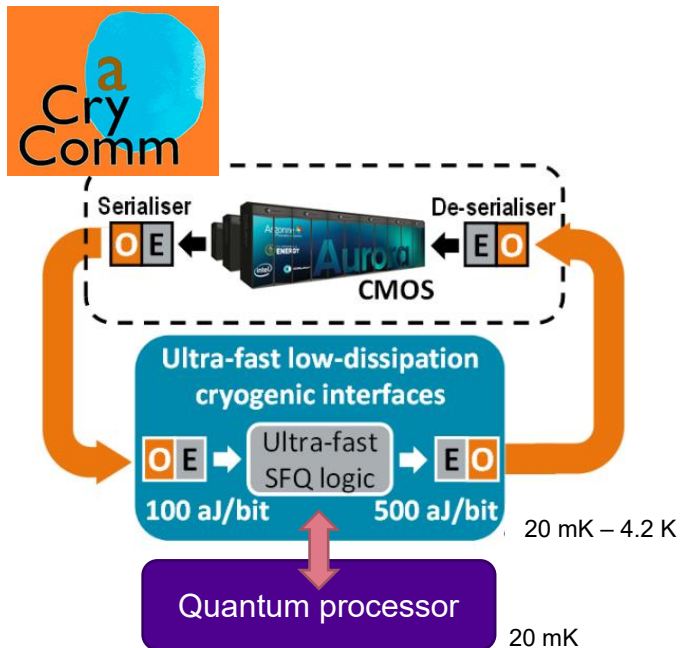


Narrow linewidth laser



New approaches for cryogenic optical links

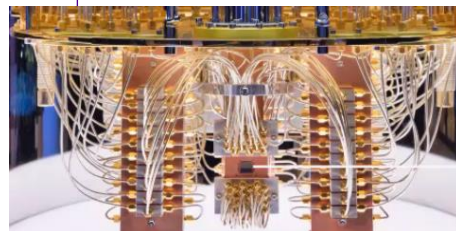
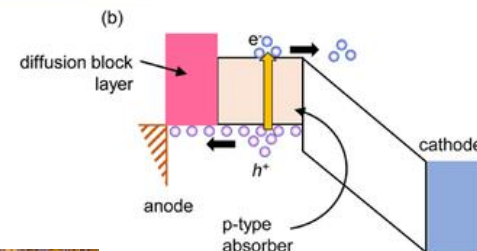
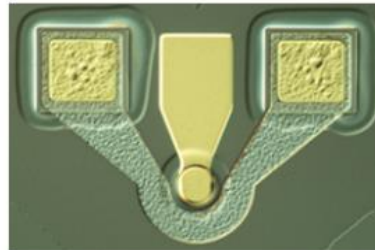
Interfacing quantum and classical computers



<https://www.acrycomm.eu/>

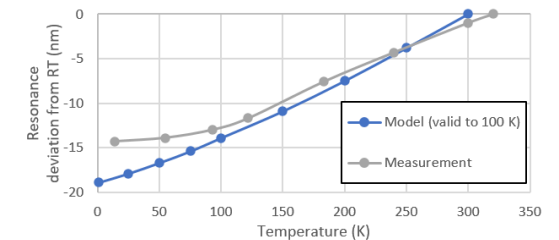
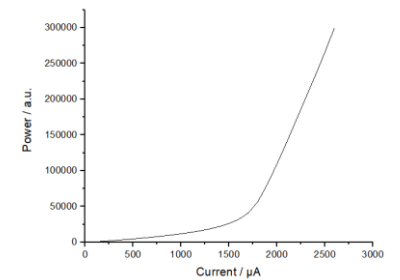
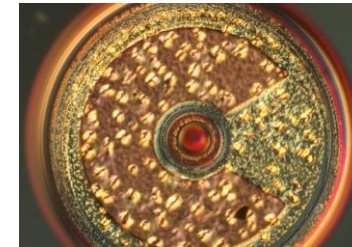
Optical-to-electrical conversion

- Based on uni-traveling carrier photodiode (UTC-PD)
- Exploration of high electron mobility materials at 4.2 K
- **Target for 100 GHz @ 4.2 K**



Electrical-to-optical conversion

- Based on cryogenic VCSEL
- Exploration of 4.2 K operation and miniaturization beyond SoA
- Proof-of-concept demonstrated (2022)



Senior Research Fellow
Dr. Teemu Hakkarainen

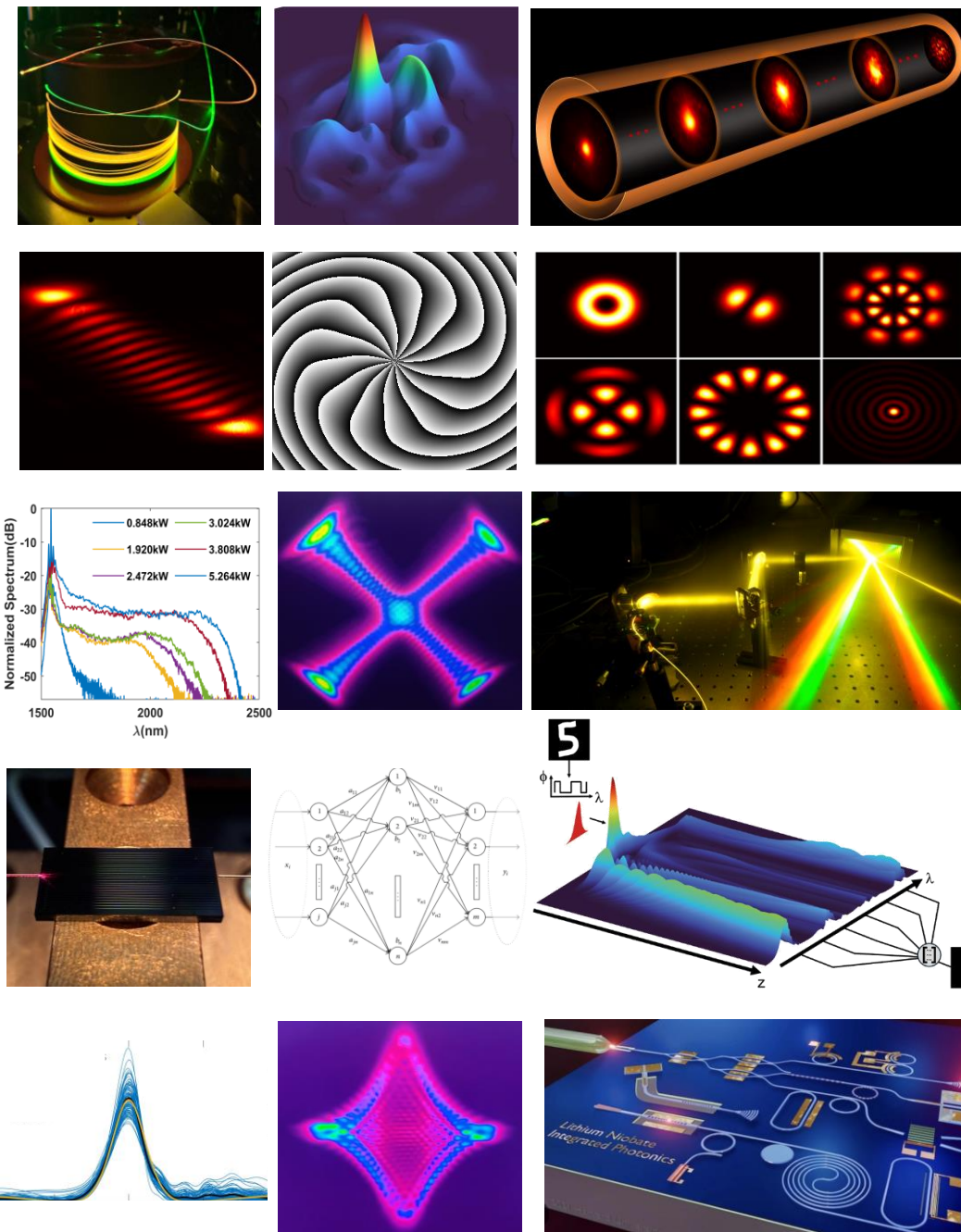
Ultrafast Photonics Group

Advanced compound materials and heterostructures

- Waveguided nonlinear light generation, wavelength conversion, structured light
- Ultrafast, complex-field diagnostics
- Machine-learning control & optical computing

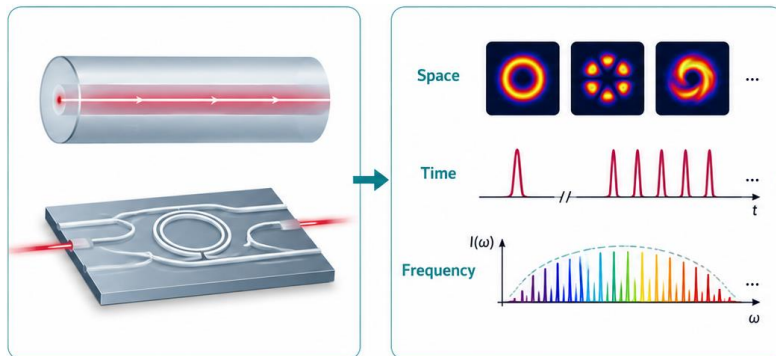
**Optical fibers (single-mode, multimode, specialty fibers),
from UV to mid-IR**

Thin-film lithium tantalate chips



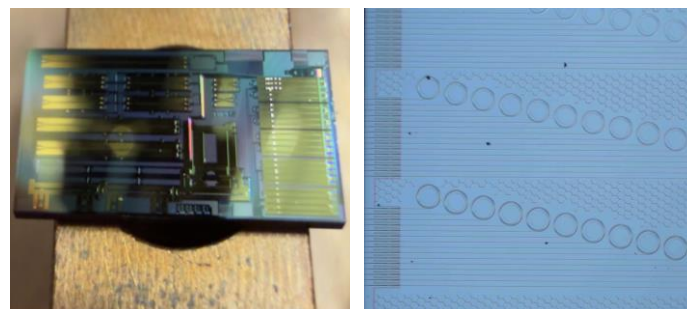
From physics-rich platforms to on-chip nonlinear functionalities

Physics-rich platforms



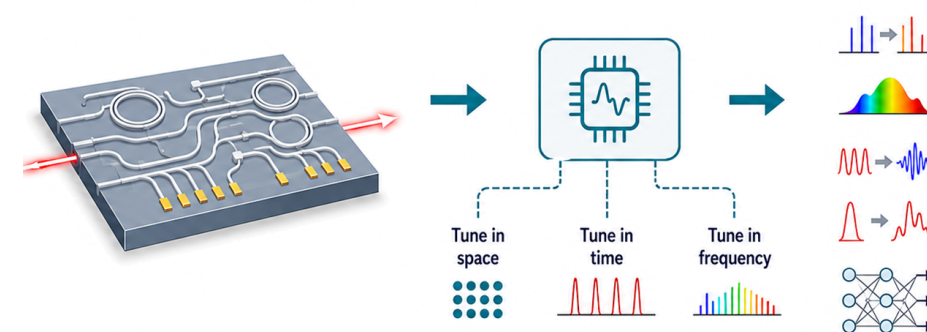
- Guided-wave systems (fibers, waveguides)
- Structuring light in space, time & frequency
- Multimode & nonlinear systems

Integrated nonlinear photonics



- Nonlinear functionality on chip-scale platforms
- TFLT, SiN, LiNbO₃, AlN

Programmable functionalities



- Frequency conversion, supercontinuum generation, parametric gain, modulation, pulse shaping, neuromorphic computing
- Flexible and reconfigurable platforms

Use ultrafast nonlinear optics as an active layer for applications in sensing and chip-scale information processing

Enabling nonlinear optical functions on emerging chip platforms

Advanced experimental capabilities

- Ultrafast optical testing (CW, ns, ps and fs excitation; telecom, near-IR and visible wavelength ranges)
- Advanced temporal, spectral and spatial diagnostics (FROG, spectral interferometry, off-axis holography, OSA/camera-based measurements)
- Programmable optical excitation (Spatial light modulators, electro-optic modulators, spectral waveshaping)
- Closed-loop optimization and machine-learning control

Chip / platform development routes

- TFLT and nonlinear photonic chips via clean-room / foundry collaborations
- Input on device specifications for nonlinear optical functions
- dispersion, phase matching, coupling, power handling
- Periodic poling and quasi-phase-matching concepts
- Experimental feedback loop between design, fabrication and optical testing

Know-how

- Nonlinear and ultrafast photonics
- Waveguide and integrated photonic device physics
- Numerical modelling of nonlinear propagation and device performance
- Machine-learning-assisted control, optimization and data analysis

What fellows get: a bridge between materials/device and experimentally validated nonlinear photonic functions

Possible research directions

The ultrafast photonics groups is an excellent match for fellows who want to connect materials, integrated photonics, and nonlinear ultrafast functionality

Examples where the group can host or co-supervise projects area:

01 TFLT nonlinear building blocks	Efficient wavelength conversion, supercontinuum generation, and pulse shaping on low-loss thin-film platforms
02 Dielectric / TFLT interfaces	Use heterostructure integration to combine gain, nonlinearity, guiding, and high-speed control
03 Mid-IR photonic sources	Chip-compatible nonlinear sources for integrated molecular sensing (mid-IR supercontinuum and frequency-comb, optical parametric sources etc.)
04 Optical computing	Physical nonlinear transformations as computing layers for reservoir / extreme-learning machine concepts (nonlinear waveguides, semiconductor optical amplifiers, microresonators, multimode photonic circuits, hybrid photonic-electronic readout etc.)
05 Programmable photonic chips	Closed-loop machine-learning control for nonlinear devices and photonic-electronic systems (modulators, filters, nonlinear waveguides, OPO/OPA sources, frequency-comb generators, photonic-electronic feedback circuits etc.)

Webiste: <https://research.tuni.fi/ufo-en/>

Contact: goery.genty@tuni.fi

CMOS AND BEYOND: DEVICES AND SYSTEMS RESEARCH GROUP



Fab Lead: Sozaraj Rasappa, Currently at SiPFab



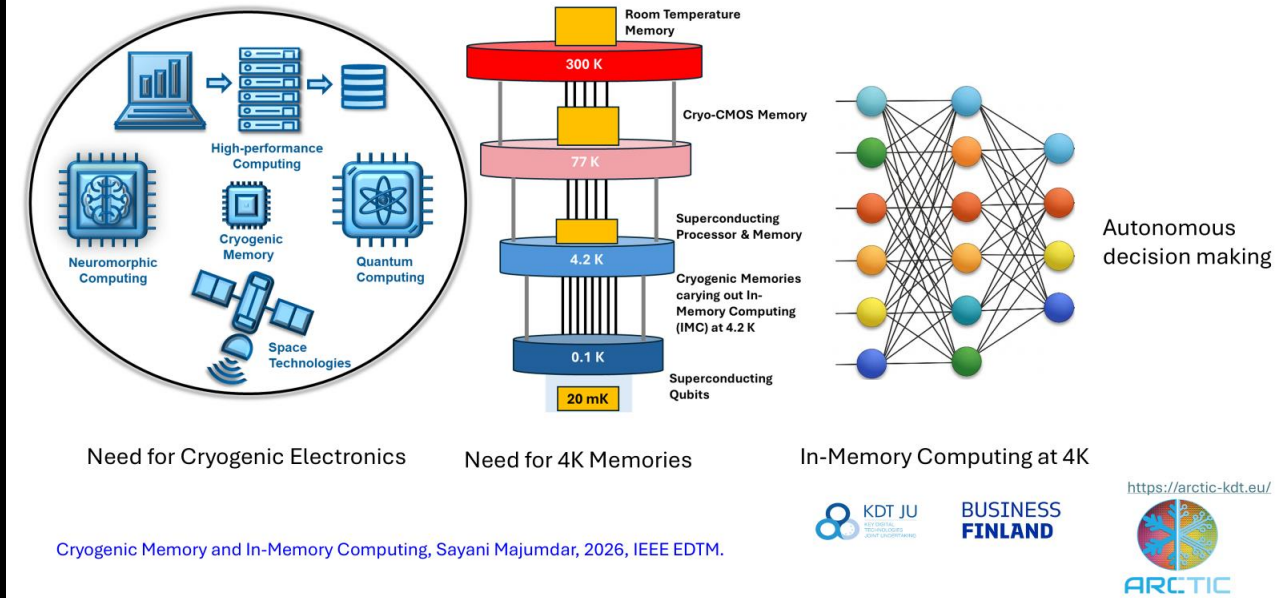
Group composition, Postdocs: 2, PhD Students: 6, Masters students: 2

Details of project portfolio: <https://research.tuni.fi/cmos-and-beyond/>

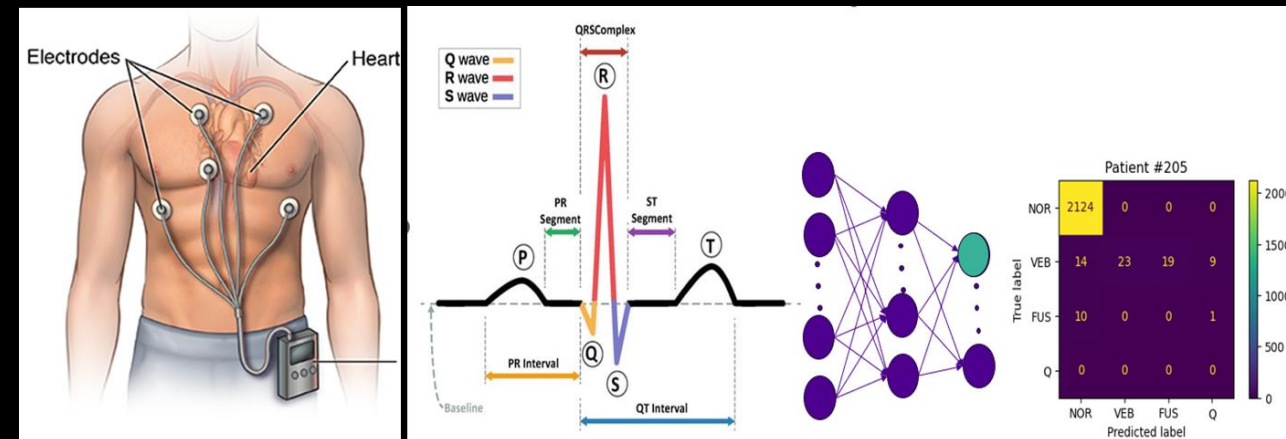
FUTURE COMPUTING HARDWARE – NEUROMORPHIC EDGE AI

- Memory, Sensing and Logic components and circuit development with special focus on Device and Systems-level *Performance Reliability*.
- AI-driven Materials and Process design for next generation of Computing Devices.
- Back-end compatible Low thermal Budget Ferroelectric and Semiconductors Device fabrication, Defect Characterization and Analysis, Physics-based Modelling, Yield and Reliability Analysis.
- Non-volatile Memories and In-Memory Computing operating down to deep cryogenic temperatures
- 3D integrated Sensor, Memory and Logic for Edge-AI HW
 - Health care (Arrhythmia Detection using SNN)
 - Autonomous Vehicle (Multi-sensor fusion and decision making)

Cryogenic Memory and IMC for Quantum & Space



Low-power AI at the edge for health – Arrhythmia detection in SNN

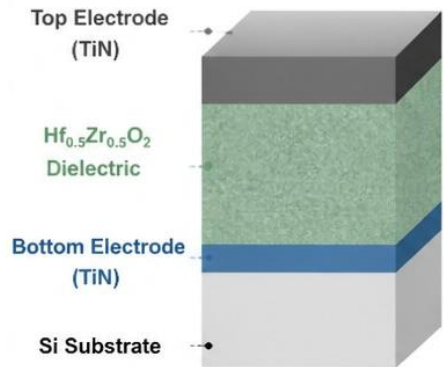




DEVICES FOR FUTURE COMPUTING HARDWARE

Sayani Majumdar, Assoc. Professor, sayani.majumdar@tuni.fi

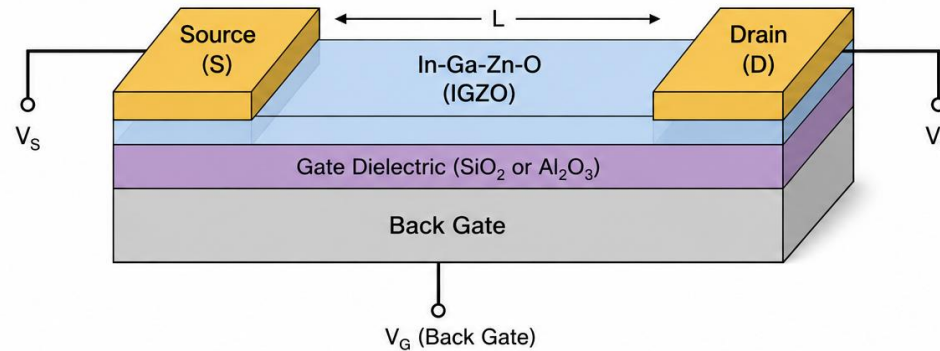
Hf_{0.5}Zr_{0.5}O₂ Thin Film Capacitor



$$C = \epsilon_0 \epsilon_r \frac{A}{d}$$

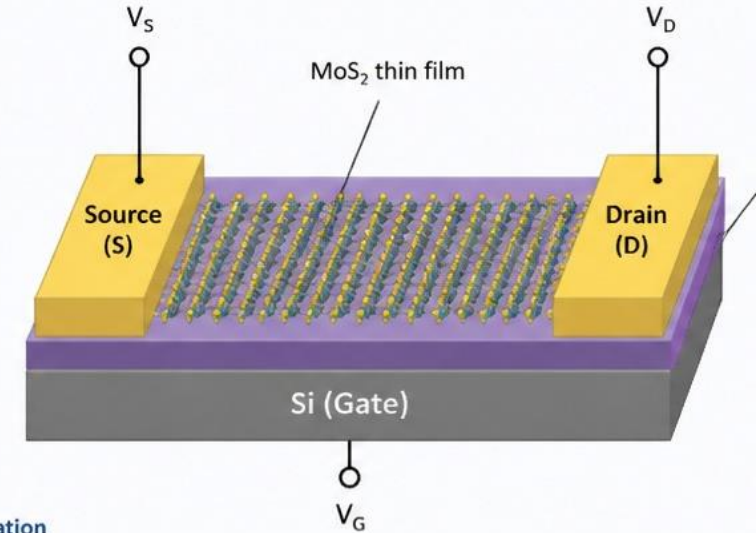
C : Capacitance
 ϵ_r : Dielectric constant
 A : Area
 d : Dielectric thickness

IGZO FeFET



MoS₂ Thin Film Transistor (FET)

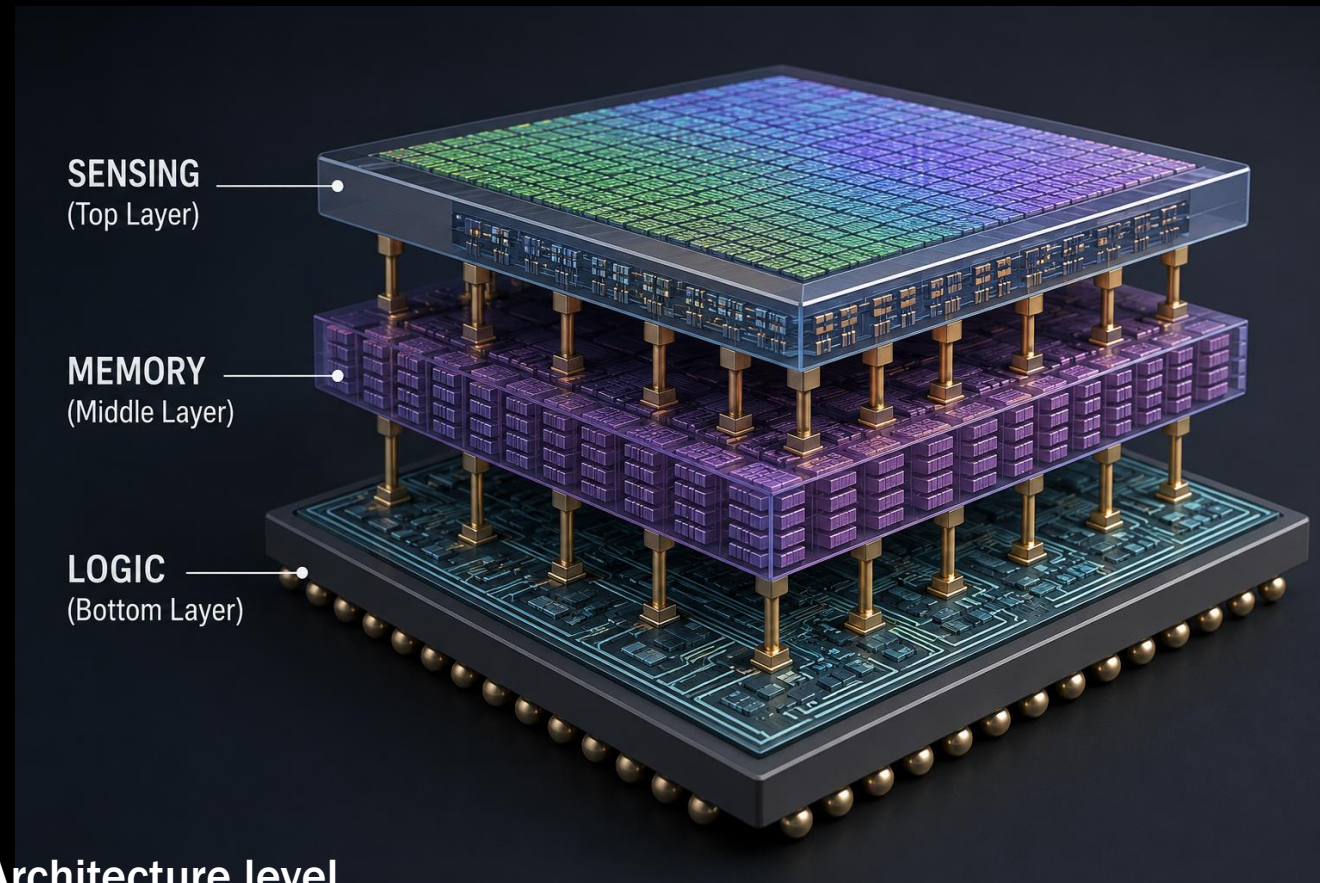
1. Device schematic



Operation

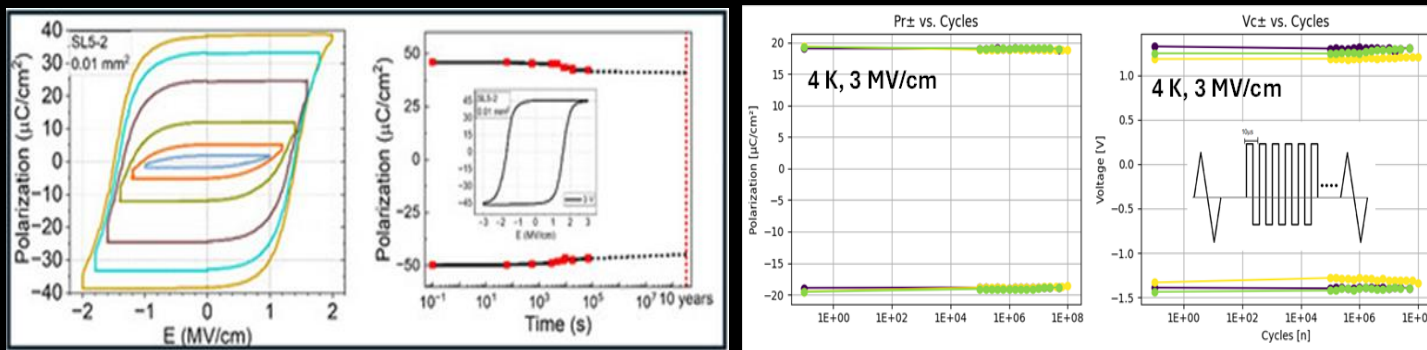
**DEVELOPMENT TARGETS: 1) LOW-POWER, 2) NANO-SCALE, 3) 3D-
INTEGRATION FOR RESISTIVE AND CAPACITIVE IN-MEMORY COMPUTING
4) SELF-POWERED 5) HARDWARE SECURITY 6) NOVEL FUNCTIONALITIES**

FULLY INTEGRATED FUTURE COMPUTING HARDWARE

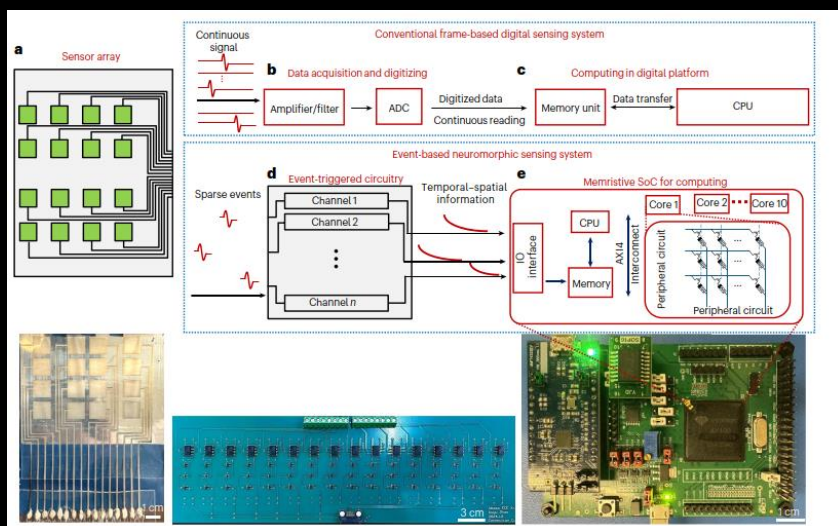


Innovation at both Device and Architecture level

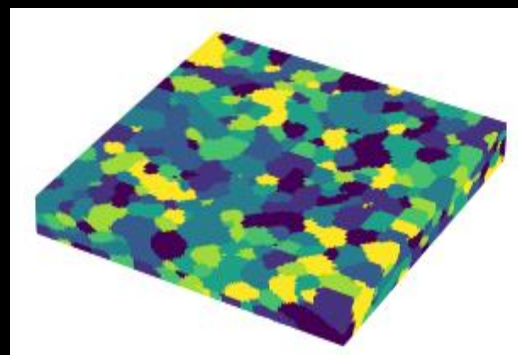
BEYOND STATE-OF-THE-ART RESULTS FOR FUTURE COMPUTING HARDWARE



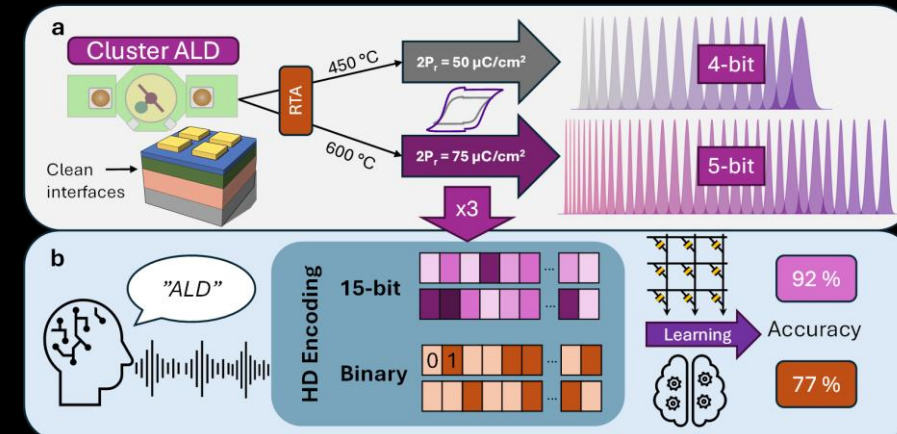
Low operating voltage NVM down to 4K, Adv Mater Tech, e02027, 2026



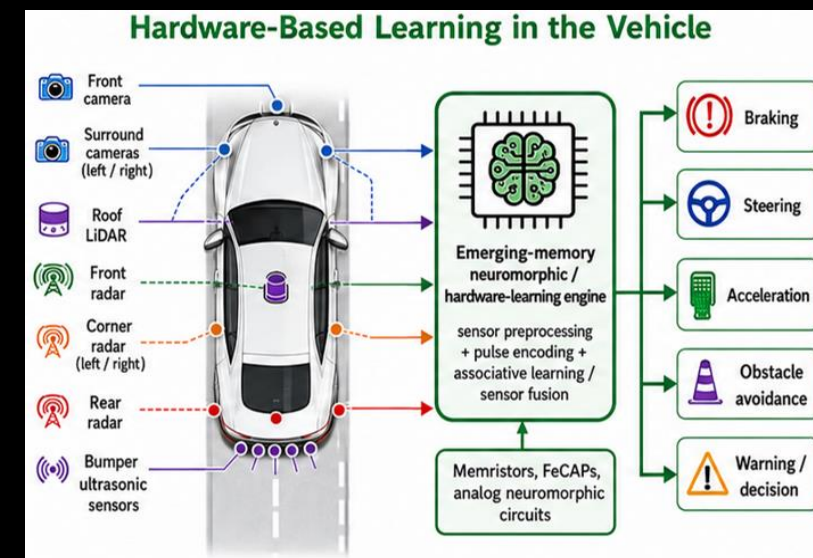
Near - sensor Computing, Nature Sensors 1, 163, 2026



Physics based compact model, Adv. Electron. Mater. 11, 2400840, 2025



Capacitive IMC and HDC, Nature Microsys. and Nanoeng. (in press, 2026)



Sensor Fusion and decision making at the Edge, Adv Intel Sys. 2025, Adv Electron Mater 2026, npj Unconventional Computing



Professor Matti Mäntysalo

Electronics, 0000-0002-7780-6454

- Professor at the **Faculty of Information Technology and Communication Sciences** in the Electrical Engineering Unit, head of Electronics Research Centre
- **Research focus:** Redefining electronics materials, fabrication, and form factors to enable sustainable and scalable electronic systems
- **Expertise in:** Printed and additive electronics, thin-film devices, sensors, supercapacitors, and heterogeneous integration.
- **Collaboration offering:** From early concept and materials to integrated demonstrators and system-level validation, with emphasis on scalability and real-world deployment.

Keywords:

Printed and additive;
Flexible and stretchable;
Sustainable electronics;
Biobased and low-energy;
thin-film devices
matti.mantysalo@tuni.fi
+358 (0)40 7576 800

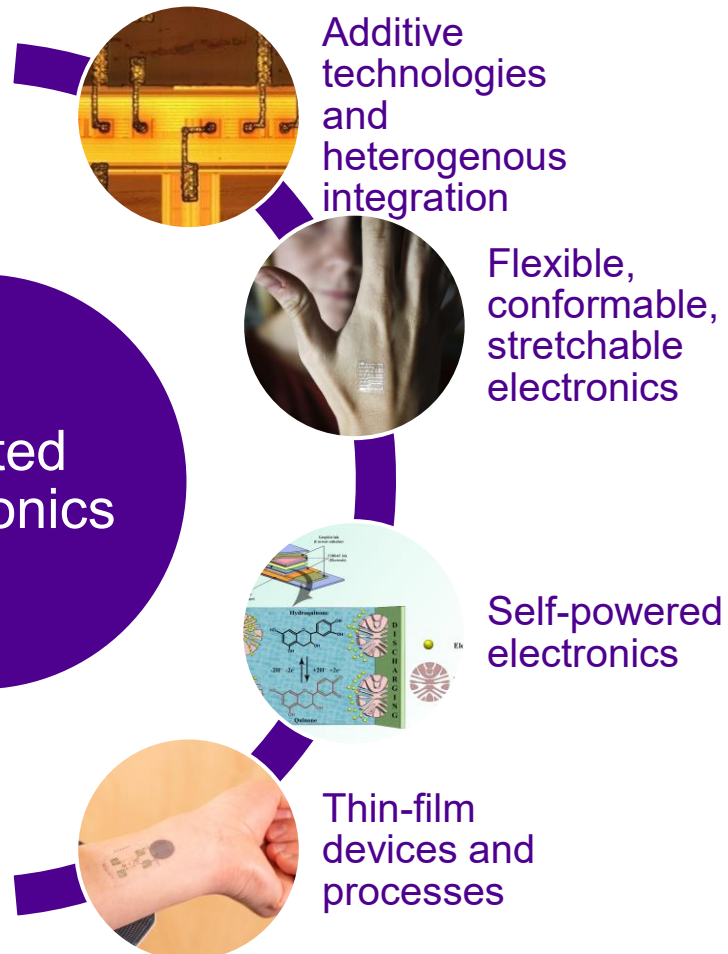




Prof. Matti Mäntysalo
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<https://research.tuni.fi/lfe/>

Prof. Mäntysalo's research

Focus and activities



FutureChips - related

Interconnections: replace wire-bonding, inkjet SiP, processing on wafers

Stretchable interconnections: geometry engineering, modeling and characterization

Transparent sensors: healthcare sensors

Supercapacitor: Electrode materials engineering; Non-toxic electrolyte

Energy harvesting: Piezo- and triboelectric nanogenerators; low-power circuits

Thin-film transistors on flexible and conformable substrates, diode, novel Atomic-Layer-Deposition processes

Heterogenous integration

JOURNAL OF THE
ELECTRON DEVICES SOCIETY

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Digital Object Identifier 10.1109/JEDS.2017.2764498

Electrical Contacts in SOI MEMS Using Aerosol Jet Printing

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(19) United States

(12) Patent Application Publication
KUISMA et al. (10) Pub. No.: US 2017/0166440 (43) Pub. Date:

(54) MICROELECTROMECHANICAL DEVICE AND METHOD FOR MANUFACTURING IT

(71) Applicant: MURATA MANUFACTURING CO., LTD., Nagaokakyo-shi (JP)

(72) Inventors: Heikki KUISMA, Helsinki (FI); Matti MÄNTYSALO, Lempäälä (FI)

(21) Appl. No.: 15/372,660

(22) Filed: Dec. 8, 2016

(30) Foreign Application Priority Data

Dec. 15, 2015 (FI) 20155948

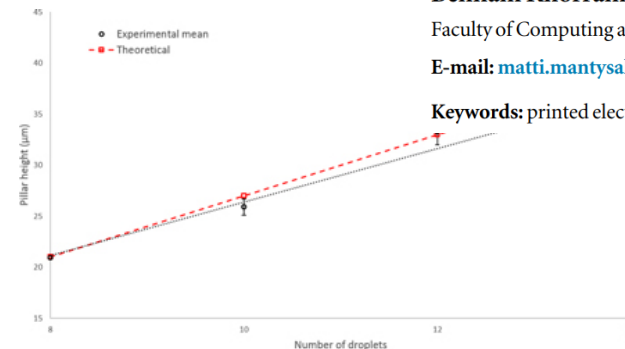
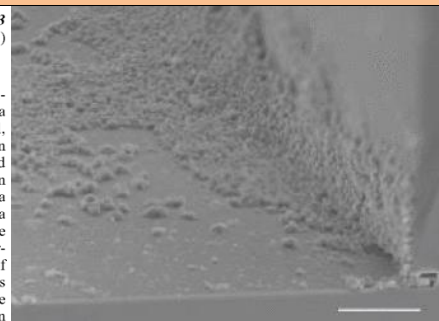
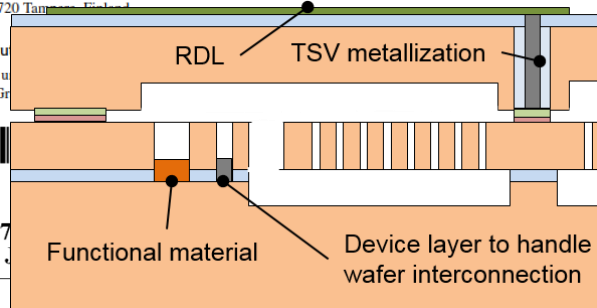
Publication Classification

(51) Int. Cl. B81B 7/00 (2006.01) B81C 1/00 (2006.01)

(52) U.S. CL. CPC B81B 7/0006 (2013.01); B81C 1/00373 (2013.01)

(57) ABSTRACT

A device and method utilizes interconnecting layers separated by an insulating layer. A layered structure comprises a first and a second layer of electrically conductive material, and a third layer of electrically insulating material between them. A via trench is fabricated that extends from the second layer through the third layer into the first layer, a surface on the first layer of electrically conductive material forming a bottom surface of the via trench. An ink-jetting set-up for a mixture of liquid carrier and nanoparticles of conductive material is formed, and a specific process period is determined. Capillary flow of nanoparticles to peripheral edges of an ink-jetted blob of said mixture is induced. The mixture is ink-jetted into a blob on the via trench; the layered structure is heated to evaporate the liquid carrier. The interconnection element is higher at a certain point than between opposing side walls.



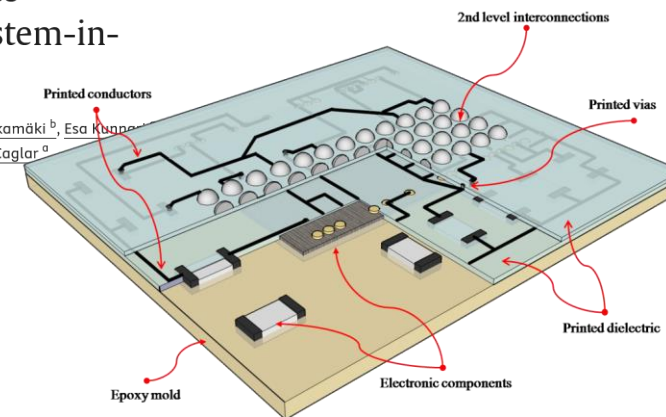
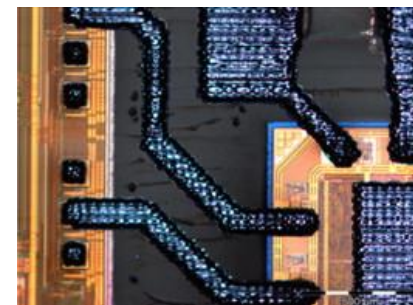
Microelectronic Engineering

Volume 87, Issue 11, November 2010, Pages 2382-2390



Utilizing inkjet printing to fabricate electrical interconnections in a system-in-package

Ville Pekkanen^a, Matti Mäntysalo^a, Kimmo Kaija^a, Pauliina Mansikkamäki^b, Esa Kuopio^a, Katja Laine^a, Juha Niittynen^a, Santtu Koskinen^a, Eerik Halonen^a, Umur Caglar^a



Flexible and Printed Electronics

<http://DOI.org/10.1088/2058-8585/aa9171>

PAPER

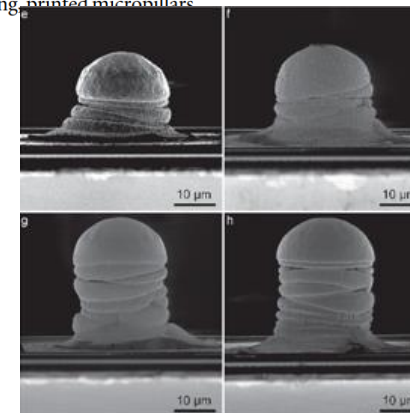
Inkjet printed metallic micropillars for bare die flip-chip bonding

Behnam Khorramdel¹, Thomas M Kraft¹ and Matti Mäntysalo¹

Faculty of Computing and Electrical Engineering, Tampere University of Technology, Tampere, FI-33720, Finland

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Keywords: printed electronics, inkjet, microelectronics packaging, 3D printing, printed micropillars



<http://DOI.org/10.1109/JEDS.2017.2764498>

<https://doi.org/10.1016/j.mee.2010.04.013>

Thin-film devices and processes

ACS APPLIED
ELECTRONIC MATERIALS

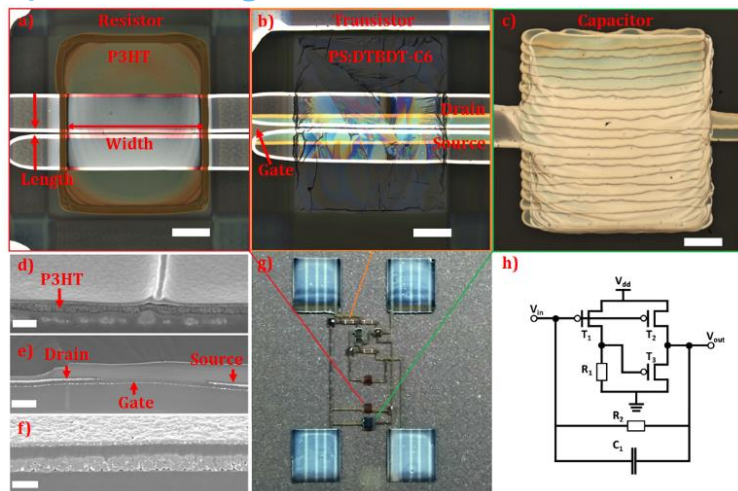
JOURNAL OF THE
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The review of this paper was arranged by Editor S. Vaziri.
Digital Object Identifier 10.1109/JEDS.2019.2915028

A Fully Printed Ultra-Thin Charge Amplifier for On-Skin Biosignal Measurements

MIKA-MATTI LAURILA¹, HIROYUKI MATSUI², REI SHIWAKU², MIKKO PELTOKANGAS³, JARMO VERHO³,
KAREM LOZANO MONTERO¹, TOMOHITO SEKINE², ANTTI VEHKAOJA³, NIKU OKSALA^{3,4,5},
SHIZUO TOKITO², AND MATTI MÄNTYSALO¹ (Member, IEEE)

<https://doi.org/10.1109/JEDS.2019.2915028>



Nano Energy

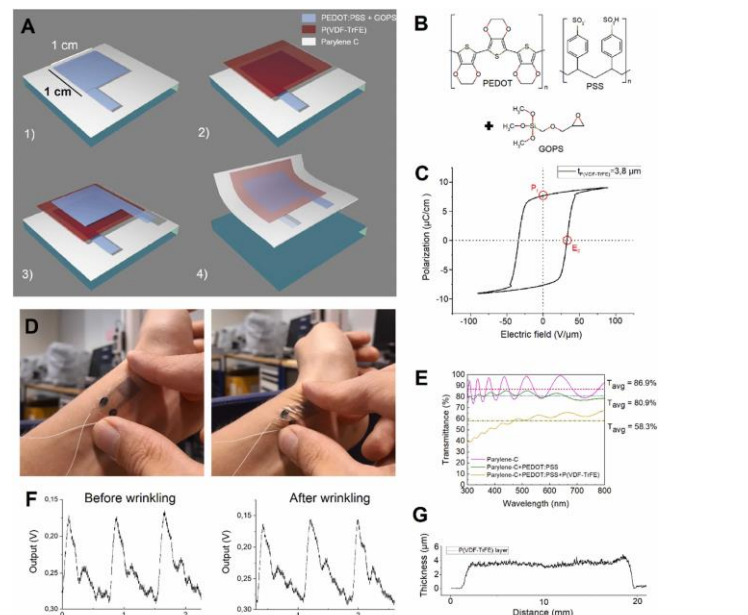
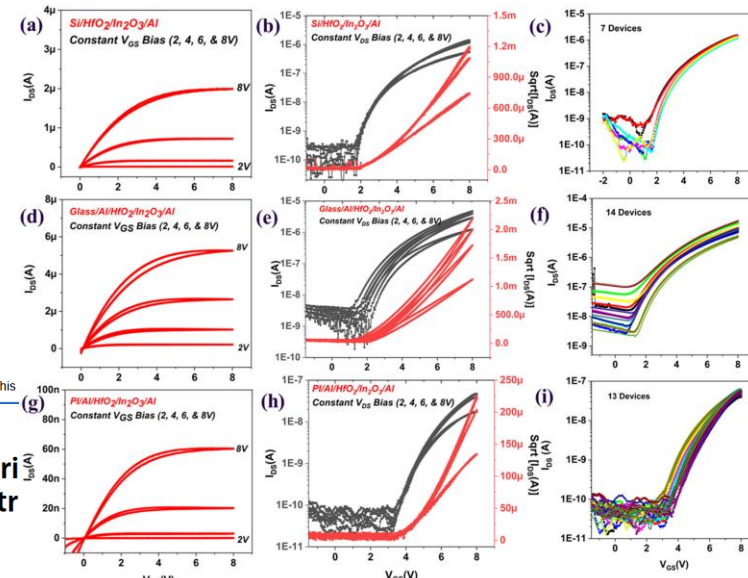
Volume 102, November 2022, 107625



Self-powered, high sensitivity printed e-tattoo sensor for unobtrusive arterial pulse wave monitoring

Mika-Matti Laurila^a, Mikko Peltokangas^{b,c}, Karem Lozano Montero^a,
Jarmo Verho^b, Mira Haapala^{b,c}, Niku Oksala^{b,c,d}, Antti Vehkaoja^{b,c}, Matti
Mäntysalo^a

<https://doi.org/10.1016/j.nanoen.2022.107625>



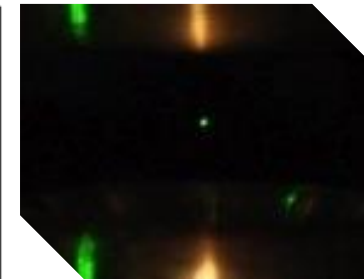
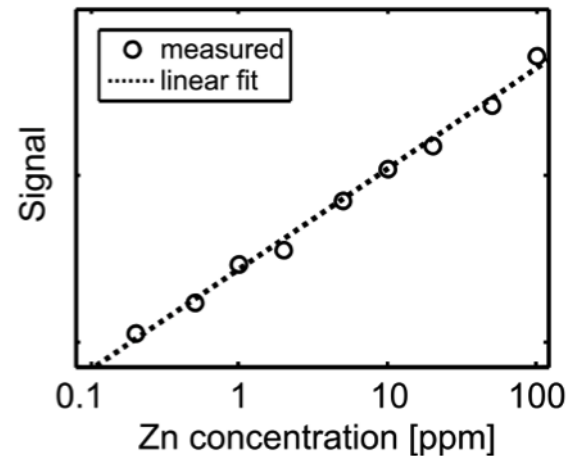
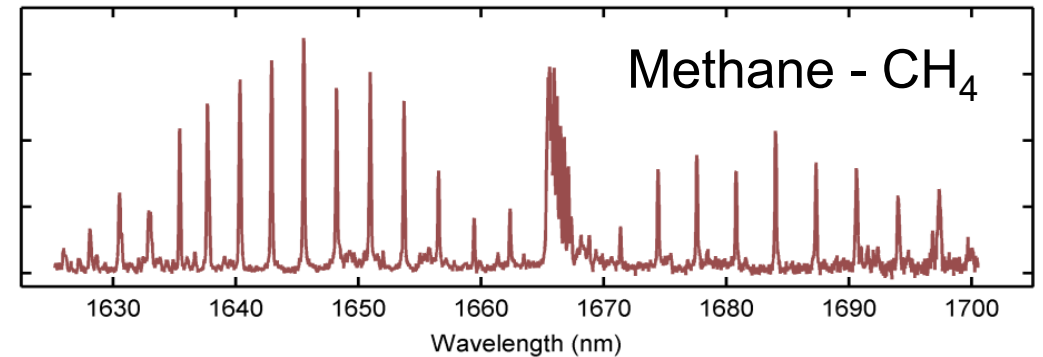
My offering

- Access to world-class infrastructure:
 - Our Lab (LFE) is a part of national Printed Intelligence Infrastructure ([PII](#))
 - Infrastructure funding RCF FIRI 2019-2028
 - See details (<https://research.tuni.fi/lfe/>): PrintLab; Thin-Film fabrication
- Research:
 - **Additive technologies and heterogenous integration** enables new heterogeneous integration paradigms by combining diverse materials and technologies into compact 3D architectures with improved performance and lower cost
 - **Thin-film devices and circuitry** enabled by advanced ALD processes provide precise materials engineering and conformal nanoscale layer deposition, opening new opportunities for flexible electronics, emerging device architectures, and heterogeneous integration

Applied Optics research group

Prof. Juha Toivonen

- Gas sensing
 - Atmospheric gases: methane, acetylene, CO_2 , NO, NO_2 ,...
 - Combustion gases: KCl, NaCl, KOH, PbCl_2 ,...
- Elemental analysis
 - Zinc content in water
 - Carbon content in soil
 - Bromium content in plastics
- LIDAR applications
 - Wind speed, humidity, temperature
 - Air pollution $\text{PM}_{2.5}$, CO_2
- Optical imaging of radioactive sources
- Drinking water quality analytics with fluorescence



Patents

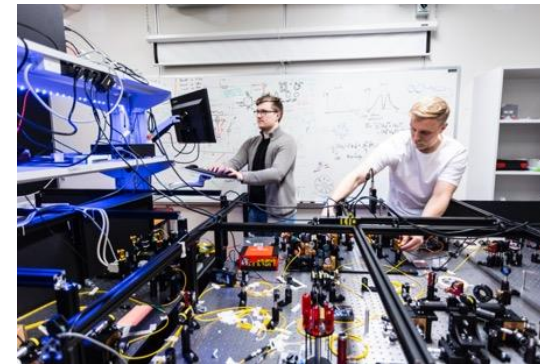
- granted 4
- pending 3



State-of-the-art Facilities



- Material growth and characterization
- Micro- and nanofabrication
- Measurement and testing
- Fiber-optics
- Coherent light sources
- Photonic integration
- Quantum optical technologies



Wire, die and flip-chip bonding, Microassembly

- ficonTEC BL2000 flip-chip bonder
- West Bond die bonder
- K&S Maxµm Ultra automatic wire bonder
- West Bond semi-automatic wire bonder
- LPKF ProtoFlow S solder oven
- ficonTEC CL1500 assembly system



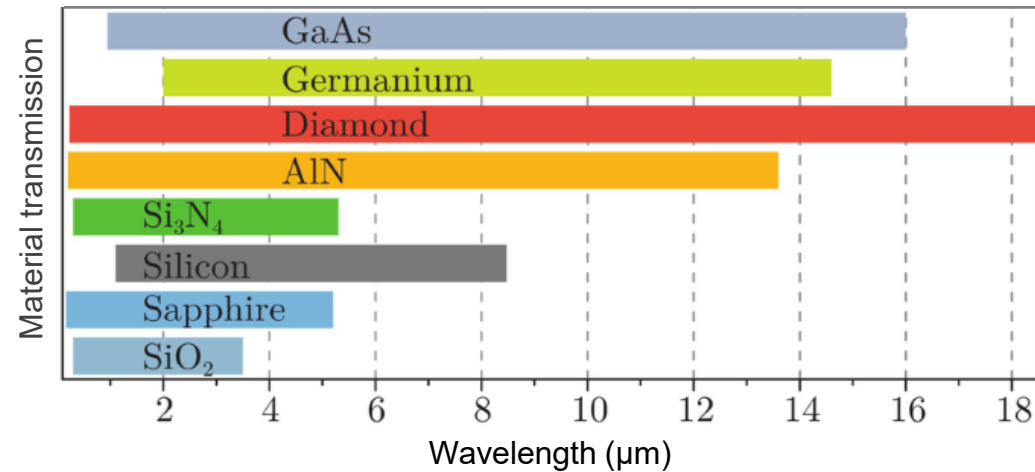
The newest installation:



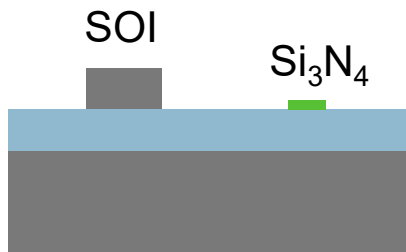
ACCURA
Flip-Chip Bonder
Plus

**High Accuracy
Automatic
Flip-Chip Bonder**

Sensing often requires Mid-IR wavelengths



Mature waveguide technologies



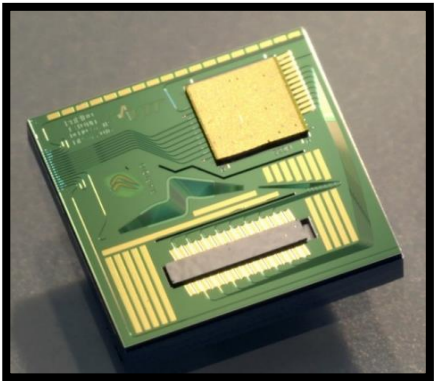
New Mid-IR waveguide technologies

Si-on-Si₃N₄ Ge-on-Si Suspended Ge, SOI and Si₃N₄

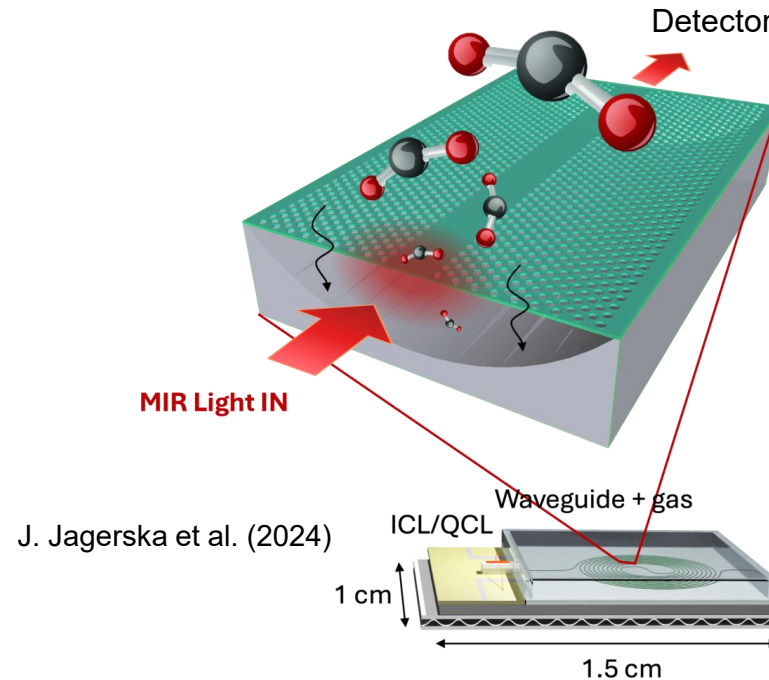


Potential project areas

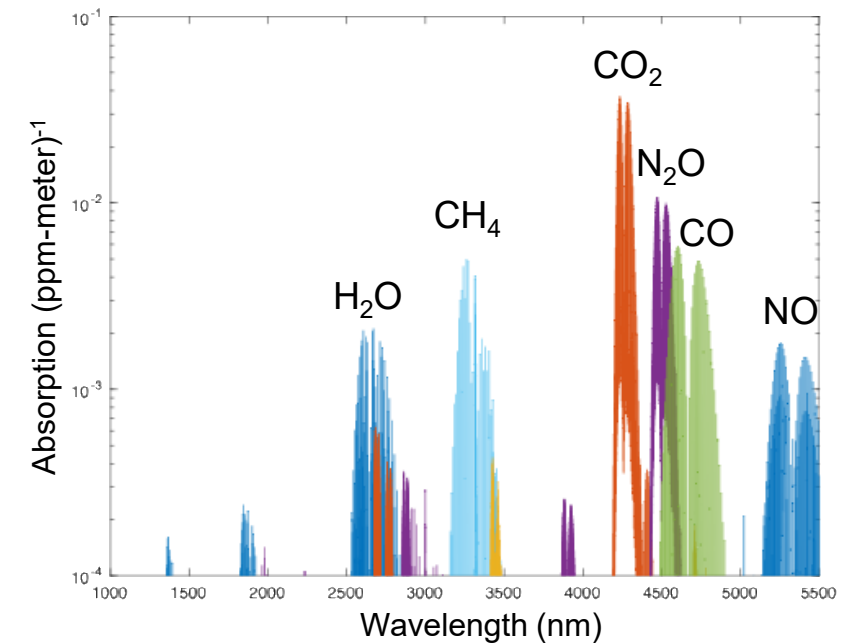
Development of mid-IR waveguides and sensing methods



Development of the integrated platform for sensing including packaging



Validation of the integrated sensing technology



Questions?

Contact: futurechips@tuni.fi

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